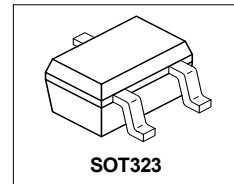


International IOR Rectifier

BAT54W

SCHOTTKY DIODE

0.2 Amp



Major Ratings and Characteristics

Characteristics	Value	Units
I_F (DC)	0.2	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 10$ ms sine	1.0	A
V_F @ 30mA DC, $T_J = 25^\circ\text{C}$	0.5	V
P_d Power Dissipation @ $T_A = 25^\circ\text{C}$	200	mW
T_J range	-65 to 150	$^\circ\text{C}$

Description/ Features

This Schottky barrier single diode is designed for high speed switching application, voltage clamping and circuit protection. Miniature surface mount packages with reduced foot print are excellent for portable application where space is limited

- Small foot print, surface mountable
- Very low forward voltage drop
- Extremely fast switching speed for high frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Case Styles

Device Marking: IR4W

DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	0.25	0.40	0.010	0.016
B	1.15	1.35	0.045	0.053
C	2.00	2.20	0.079	0.087
D	-	0.65	-	0.026
F	0.30	0.40	0.012	0.016
G	1.20	1.40	0.047	0.055
H	1.80	2.20	0.071	0.087
J	0.00	0.10	0.000	0.004
K	0.90	1.00	0.035	0.039
L	0.10	0.30	0.004	0.012
M	0.109	0.25	0.004	0.010
α	8°		8°	

Outline SOT323

BAT54W

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Voltage Ratings

Part number	Value
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	Value	Units	Conditions	
I_F Forward Current	0.2	A	DC	
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current, @ $T_J = 25^\circ\text{C}$	8.4	A	5 μs Sine or 3 μs Rect. pulse	Following any rated load condition and with rated V_{RWM} applied
	0.6	A	10ms Sine or 6ms Rect. pulse	

Electrical Specifications

Parameters	Value	Units	Conditions	
V_{FM} Max. Forward Voltage Drop (1)	0.24	V	@ 0.1mA	$T_J = 25^\circ\text{C}$
	0.32	V	@ 1mA	
V_{FM} Max. Forward Voltage Drop (1)	0.40	V	@ 10mA	
	0.50	V	@ 30mA	
	0.65	V	@ 100mA	
I_{RM} Max. Reverse Leakage Current (1)	2	μA	$V_R = 25\text{V}$	
	3	μA	$V_R = 30\text{V}$	
C_T Max. Junction Capacitance	10	pF	$V_R = 1V_{DC}$ (test signal range 100kHz to 1MHz), $T_J = 25^\circ\text{C}$	
dv/dt Max. Voltage Rate of Change (Rated V_R)	10000	V/ μs		

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions
T_J Max. Junction Temperature Range (*)	-65 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-65 to 150	$^\circ\text{C}$	
$R_{th(j-a)}$ Max. Thermal Resistance Junction to Ambient	625	$^\circ\text{C}/\text{W}$	Mounted on PC board FR4 with minimum pad size
Wt Approximate Weight	0.006	gr	
Case Style	SOT323		
Device Marking	IR4W		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

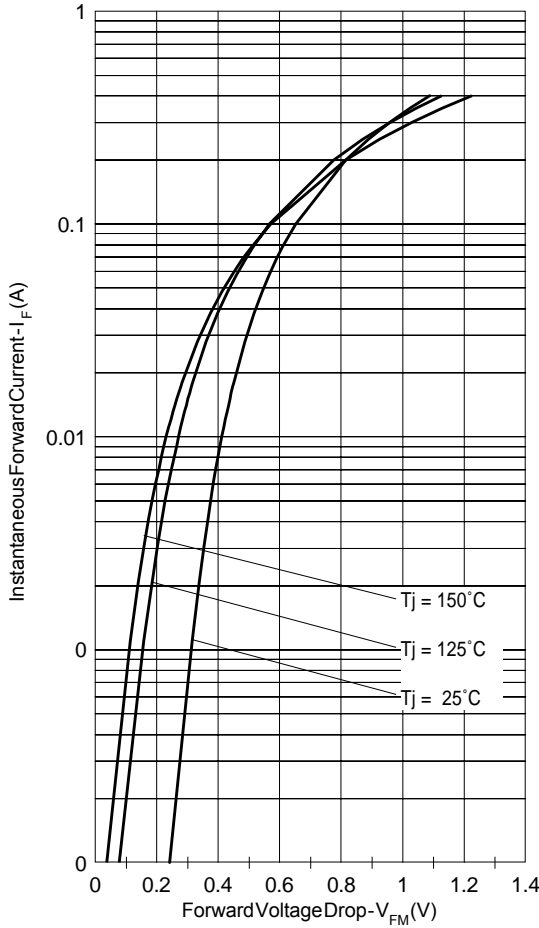


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

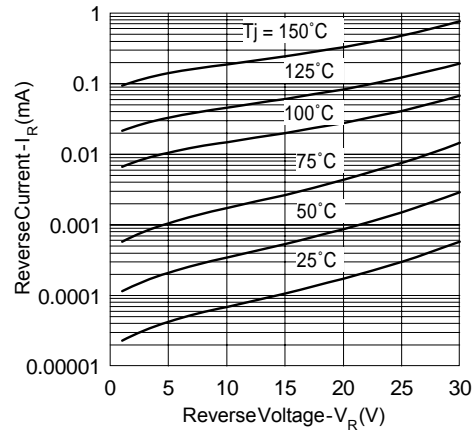


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

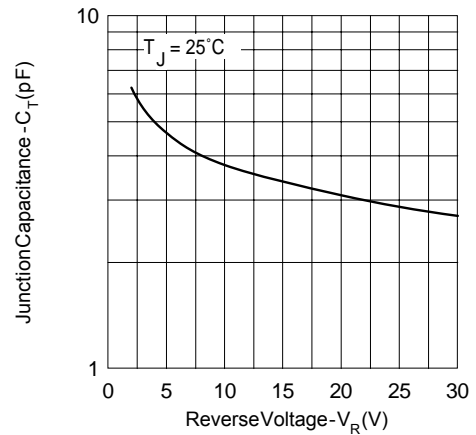


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

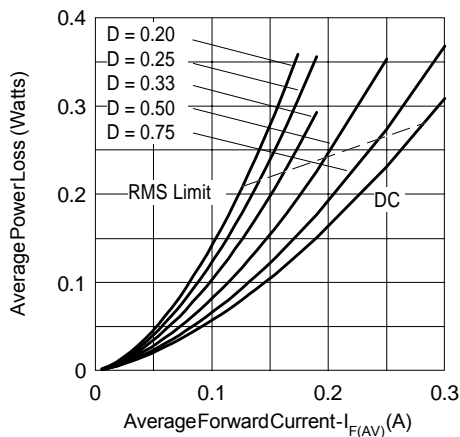


Fig. 4 - Forward Power Loss Characteristics

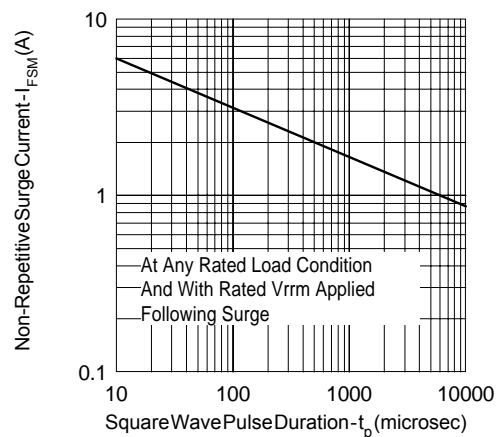


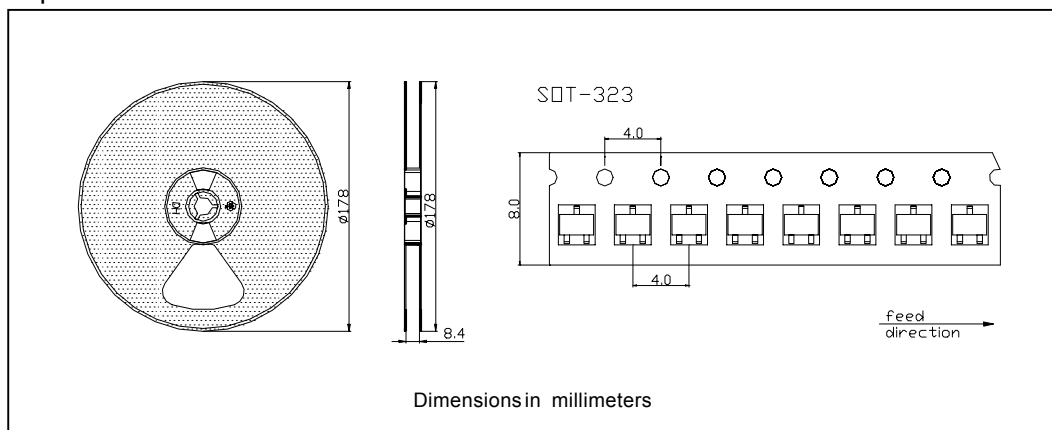
Fig. 5 - Max. Non-Repitative Surge Current

BAT54W

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International
IR Rectifier

Tape & Reel Information



Ordering Information Table

Device	Package	Marking	Configuration	Base qty	Delivery mode
BAT54W	SOT-323	IR4W	Single	3000	Tape & Reel

Data and specifications subject to change without notice.
This product has been designed for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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